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24-bit FET Bus-Exchange Switches with Schottky diode clamping



ADE-205-680 (Z)

Preliminary Rev. 0 Feb. 2002

Description

The HD74CBTS16212A devices provide 24-bits of high speed TTL-compatible bus switching or exchanging. The low on state resistance of the switch allows connections to be made with minimal propagation delay. Each device operates as a 24-bit bus switch or a 12-bit bus exchanger that provides data exchanging between the four signal ports via the data-select (S0, S1, S2) terminals.

Features

- Minimal propagation delay through the switch.
- 5 Ω switch connection between two ports.
- TTL-compatible input levels.
- Ultra low quiescent power.
 - -Ideally suited for notebook applications.
- Package type

Product code example: HD74CBTS16212ATEL

| Package type | Package code | Package suffix | Taping code |
|--------------|--------------|----------------|---------------------|
| TSSOP-56pin | TTP-56DAV | Т | EL(1,000pcs / Reel) |

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Function Table

| Inputs | nputs | | Inputs / Ou | itputs | |
|--------|-------|----|-------------|---------|--|
| S2 | S1 | S0 | A1 | A2 | Function |
| L | L | L | Z | Z | Disconnect |
| L | L | Н | B1 port | Z | A1 port = B1 port |
| L | Н | L | B2 port | Z | A1 port = B2 port |
| L | Н | Н | Z | B1 port | A2 port = B1 port |
| Н | L | L | Z | B2 port | A2 port = B2 port |
| Н | L | Н | Z | Z | Disconnect |
| Н | Н | L | B1 port | B2 port | A1 port = B1 port A2 port = B2 port |
| Н | Н | Н | B2 port | B1 port | A1 port = B2 port A2 port = B1 port |

H: High level

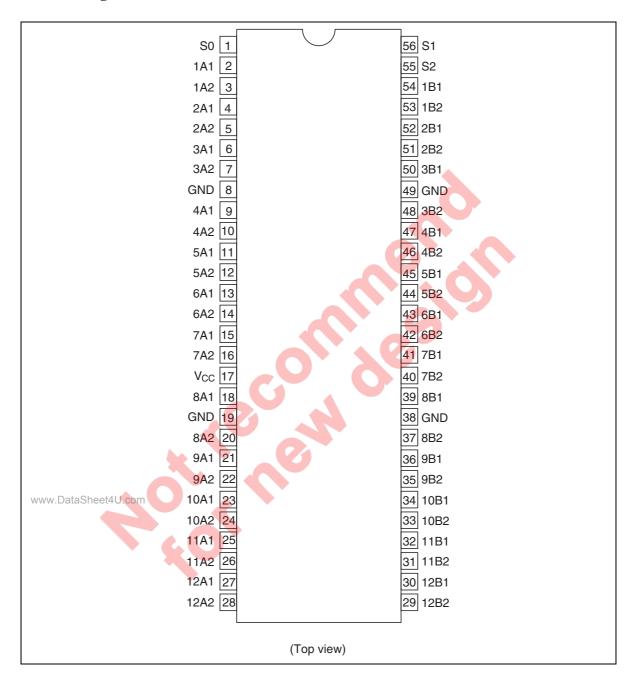
L: Low level

Z: High impedance



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Pin Arrangement



Absolute Maximum Ratings

| Item | Symbol Ratings | | Unit | Conditions |
|---|-------------------------------------|-------------|------|-------------------------|
| Supply voltage range | V _{cc} | -0.5 to 7.0 | V | |
| Input voltage range 1 | V _i | -0.5 to 7.0 | V | |
| Input clamp current | I _{IK} | -50 | mA | V ₁ < 0 |
| Continuous output current | I _o | 128 | mA | $V_{o} = 0$ to V_{cc} |
| Continuous current through V_{cc} or GND | I _{CC} or I _{GND} | ±100 | mA | |
| Maximum power dissipation at Ta = 25°C (in still air) ^{'2} | $P_{\scriptscriptstyle T}$ | 1.32 | W | |
| Storage temperature | Tstg | -65 to 150 | °C | |

Notes:

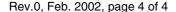
The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded even if the input and output clamp-current ratings are observed.
- 2. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

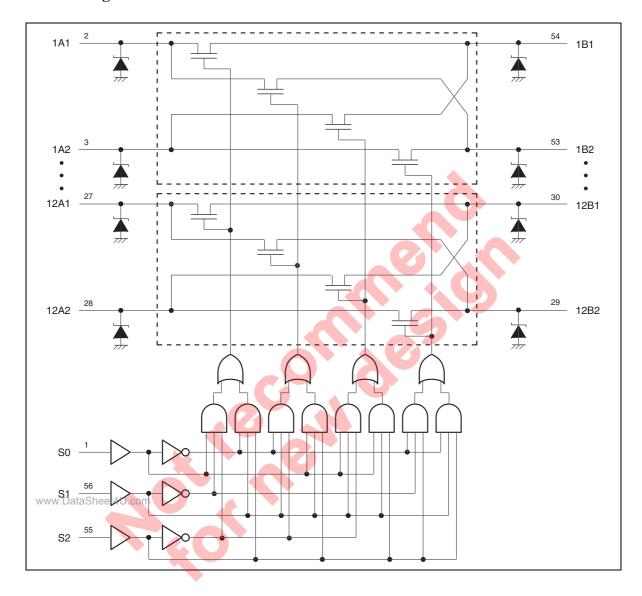
| Item | Symbol | Min | Max | Unit | Conditions |
|------------------------------------|------------------|-----|-----|--------|--------------------------------|
| Supply voltage range | V _{cc} | 4.0 | 5.5 | V | _ |
| Input voltage range | Vi | 0 | 5.5 | V | |
| Output voltage range | V _{I/O} | 0 | 5.5 | V | |
| Input transition rise or fall rate | Δt / Δν | 0 | 5 | ns / V | V _{cc} = 4.5 to 5.5 V |
| Operating free-air temperature | Та | -40 | 85 | °C | |

Note: Unused or floating inputs must be held high or low.



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Block Diagram



DC Electrical Characteristics

 $(Ta = -40 \text{ to } 85^{\circ}C)$

| Item | Symbol | $V_{cc}(V)$ | Min | Typ ^{⁺¹} | Max | Unit | Test conditions |
|--|-----------------|-------------|----------|-------------------|------|------|--|
| Clamp diode voltage | V _{IK} | 4.5 | _ | _ | -1.2 | V | $I_{IN} = -18 \text{ mA}$ |
| Input voltage | V _{IH} | 4.0 to 5.5 | 2.0 | _ | | V | |
| | V _{IL} | 4.0 to 5.5 | _ | _ | 0.8 | | |
| On-state switch resistance ² | R _{on} | 4.0 | _ | 14 | 20 | Ω | $V_{IN} = 2.4 \text{ V},$ $I_{IN} = 15 \text{ mA}$ Typ at $V_{CC} = 4.0 \text{ V}$ |
| | | 4.5 | _ | 4 | 7 | 0 | $V_{IN} = 0 V,$ $I_{IN} = 64 \text{ mA}$ |
| | | 4.5 | _ | 4 | 7 | | $V_{IN} = 0 \text{ V},$ $I_{IN} = 30 \text{ mA}$ |
| | | 4.5 | _ | 6 | 12 | | $V_{IN} = 2.4 \text{ V},$ $I_{IN} = 15 \text{ mA}$ |
| Input current | I _{IN} | 0 to 5.5 | _ | 1 | ±1.0 | μА | V _{IN} = 5.5 V or GND control inputs |
| Off-state leakage current | l _{oz} | 5.5 | -1.0 | _ | ō | μΑ | V _o = GND A or B |
| | | 5.5 | Θ | | 20 | | $V_{\overline{O}} = 5.5 \text{ V}$ A or B |
| Quiescent supply current | I _{cc} | 5.5 | / | 1 | 3 | μΑ | $V_{IN} = V_{CC}$ or GND, $I_{O} = 0$ mA |
| Increase in I _{cc} per input '3 | ΔI_{cc} | 5.5 | 1 | | 2.5 | mA | One input at 3.4 V, other inputs at $V_{\rm cc}$ or GND |

Notes: For condition shown as Min or Max use the appropriate values under recommended operating www.DataSrconditions.

- 1. All typical values are at $V_{cc} = 5 \text{ V}$ (unless otherwise noted), $Ta = 25^{\circ}\text{C}$.
- 2. Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower voltage of the two (A or B) terminals.
- 3. This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{cc} or GND.

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Capacitance

 $(Ta = 25^{\circ}C)$

| Item | Symbol | $V_{cc}(V)$ | Min | Тур | Max | Unit | Test conditions |
|----------------------------|-----------------|-------------|-----|-----|-----|------|---|
| Control input capacitance | C _{IN} | 5.0 | _ | 5 | _ | pF | $V_{IN} = 0 \text{ or } 3 \text{ V}$ |
| Input / output capacitance | $C_{I/O(OFF)}$ | 5.0 | _ | 11 | _ | pF | $V_0 = 0 \text{ or } 3 \text{ V}$ S0, S1, or S2 = V_{cc} |

Note: This parameter is determined by device characterization is not production tested.

Switching Characteristics

 $(Ta = -40 \text{ to } 85^{\circ}C)$

• $V_{cc} = 4.0 \text{ V}$

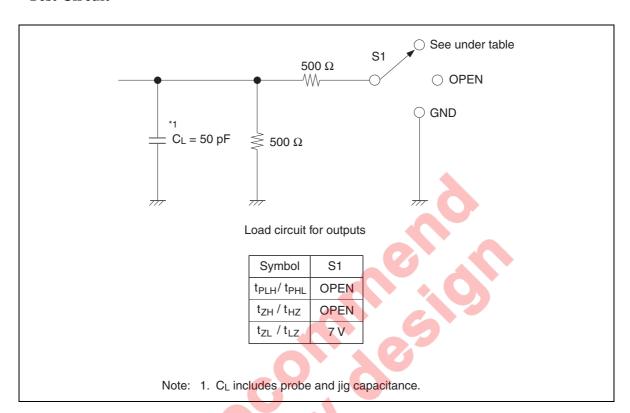
| Item | Symbol | Min | Max | Unit | Test conditions | FROM (Input) | TO (Output) |
|---------------------------|--------------------------------------|-----|------|------|--|-----------------|----------------|
| Propagation delay time *1 | t _{PLH} t _{PHL} | _ | 0.35 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | A or B | B or A |
| Propagation delay time | t _{PLH} t _{PHL} | _ | 10.0 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | S | A or B |
| Enable time | t _{zh} t _{zL} | 7 | 10.4 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | S | A or B |
| Disable time | t _{HZ} | | 9.2 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | S | A or B |

₩ww.₩ataS5:0±0.15 Vm

| Item | Symbol | Min | Max | Unit | Test conditions | FROM (Input) | TO (Output) |
|---------------------------|--------------------------------------|-----|------|------|---|-----------------|----------------|
| Propagation delay time 11 | t _{PLH} t _{PHL} | _ | 0.25 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | A or B | B or A |
| Propagation delay time | t _{PLH} t _{PHL} | 1.5 | 9.1 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | S | A or B |
| Enable time | t _{zh} t _{zL} | 1.5 | 9.7 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | S | A or B |
| Disable time | t _{HZ} t _{LZ} | 1.5 | 8.8 | ns | $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ | S | A or B |

Note: 1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

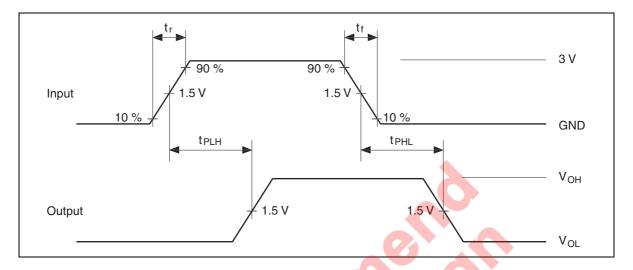
Test Circuit



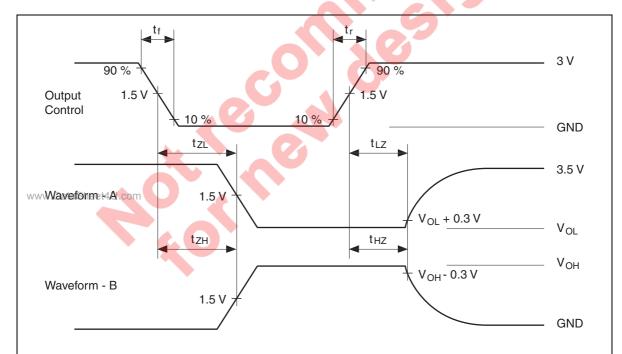
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Waveforms - 1



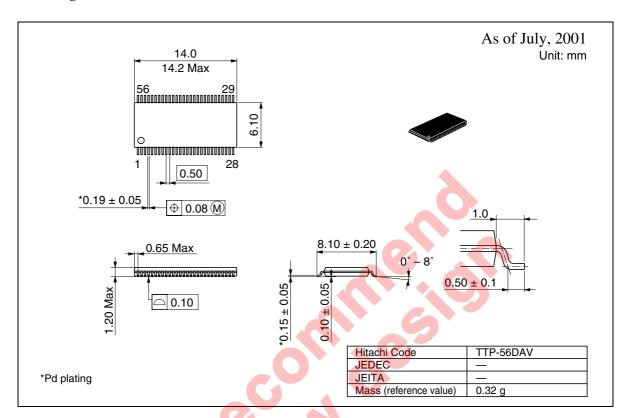
Waveforms - 2

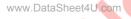


Notes: 1. All input pulses are supplied by generators having the following characteristics : PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_r \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.

- 2. Waveform A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 3. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. The output are measured one at a time with one transition per measurement.

Package Dimensions





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